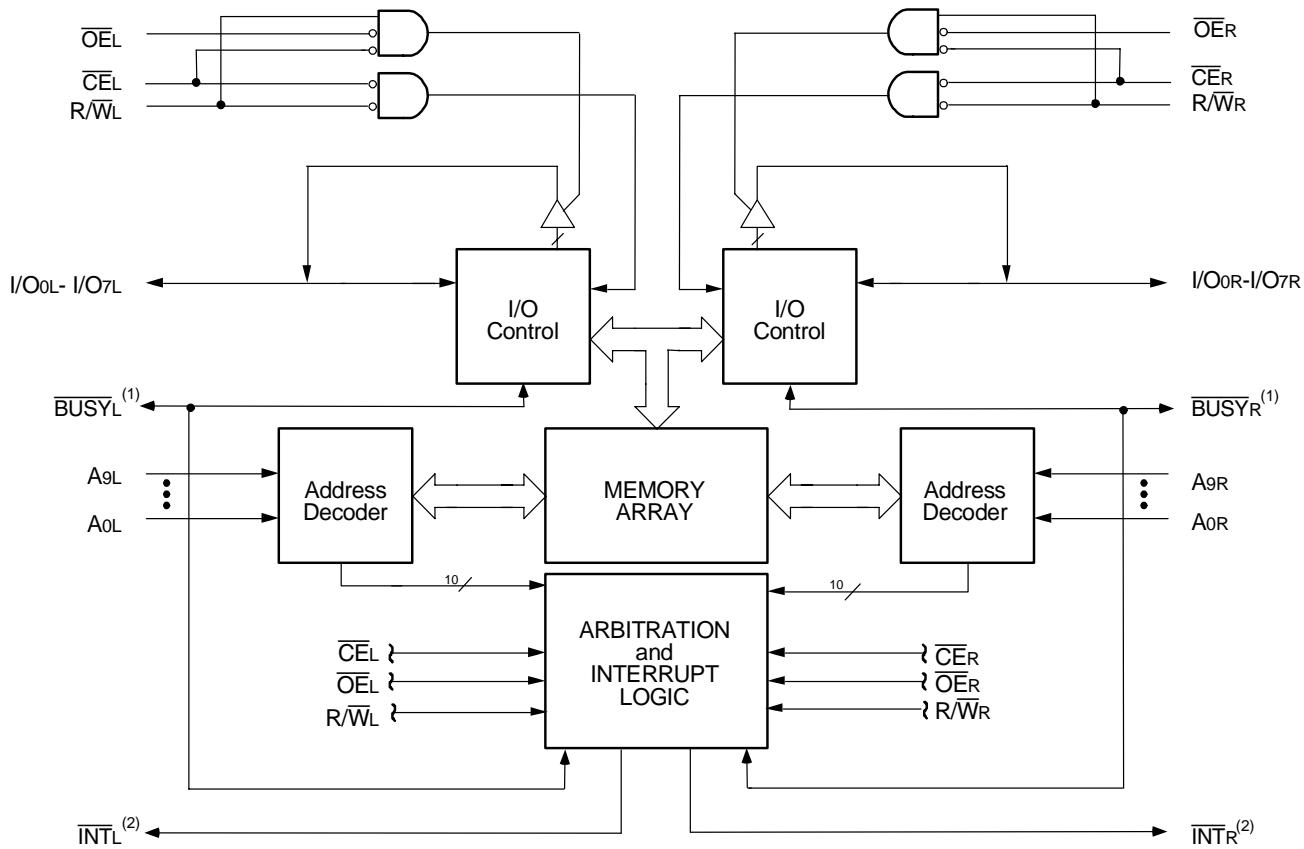


## Features

- ◆ High-speed access
  - Commercial: 25/35/55ns (max.)
  - Industrial 35ns (max.)
- ◆ Low-power operation
  - *IDT71V30S*
    - Active: 375mW (typ.)
    - Standby: 5mW (typ.)
  - *IDT71V30L*
    - Active: 375mW (typ.)
    - Standby: 1mW (typ.)
- ◆ On-chip port arbitration logic
- ◆ Interrupt flags for port-to-port communication
- ◆ Fully asynchronous operation from either port
- ◆ Battery backup operation, 2V data retention (L Only)
- ◆ TTL-compatible, single 3.3V  $\pm 0.3$ V power supply
- ◆ Industrial temperature range (-40°C to +85°C) is available for selected speeds
- ◆ Green parts available, see ordering information

## Functional Block Diagram



3741 drw 01

### NOTES:

1. IDT71V30: BUSY outputs are non-tristable push-pulls.
2. INT outputs are non-tristable push-pull output structure.

## Description

The IDT71V30 is a high-speed 1K x 8 Dual-Port Static RAM. The IDT71V30 is designed to be used as a stand-alone 8-bit Dual-Port SRAM.

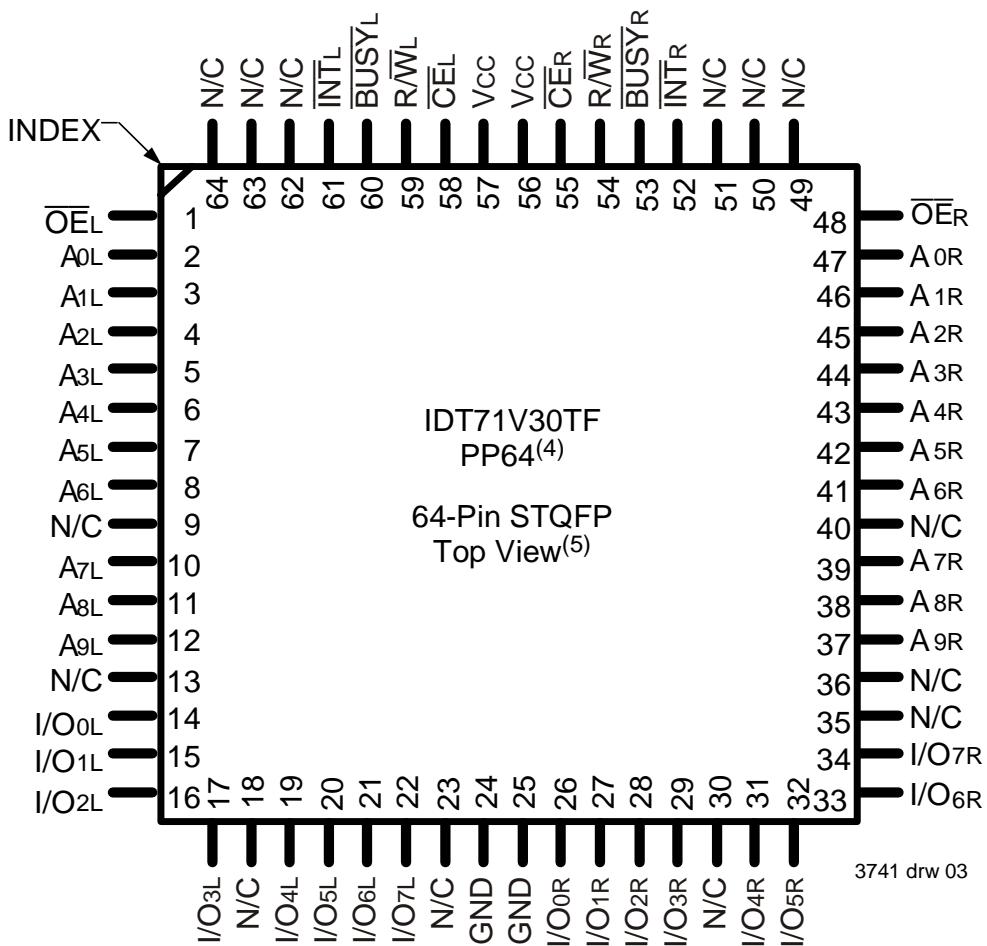
Both devices provide two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. An automatic power

down feature, controlled by  $\overline{CE}$ , permits the on chip circuitry of each port to enter a very low standby power mode.

Fabricated using CMOS high-performance technology, these devices typically operate on only 375mW of power. Low-power (L) versions offer battery backup data retention capability, with each Dual-Port typically consuming 200 $\mu$ W from a 2V battery.

The IDT71V30 devices are packaged in 64-pin STQFPs.

## Pin Configurations<sup>(1,2,3)</sup>



### NOTES:

1. All Vcc pins must be connected to the power supply.
2. All GND pins must be connected to the ground supply.
3. Package body is approximately 10mm x 10mm x 1.4mm.
4. This package code is used to reference the package diagram.
5. This text does not indicate the orientation of the actual part-marking.

## Absolute Maximum Ratings<sup>(1)</sup>

| Symbol               | Rating                               | Com'l & Ind   | Unit |
|----------------------|--------------------------------------|---------------|------|
| VTERM <sup>(2)</sup> | Terminal Voltage with Respect to GND | -0.5 to +4.60 | V    |
| TBIAS                | Temperature Under Bias               | -55 to +125   | °C   |
| TSTG                 | Storage Temperature                  | -65 to +150   | °C   |
| TJN <sup>(3)</sup>   | Junction Temperature                 | +150          | °C   |
| IOUT                 | DC Output Current                    | 50            | mA   |

### NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.  
 2. VTERM must not exceed Vcc + 0.3V for more than 25% of the cycle time or 10ns maximum, and is limited to  $\leq 20\text{mA}$  for the period of  $VTERM \geq Vcc + 0.3\text{V}$ .  
 3. This is the absolute maximum junction temperature for the device. No DC Bias.

3741tbl 01

## Recommended DC Operating Conditions

| Symbol          | Parameter          | Min.                | Typ. | Max.     | Unit |
|-----------------|--------------------|---------------------|------|----------|------|
| Vcc             | Supply Voltage     | 3.0                 | 3.3  | 3.6      | V    |
| GND             | Ground             | 0                   | 0    | 0        | V    |
| V <sub>IH</sub> | Input High Voltage | 2.0                 | —    | Vcc+0.3V | V    |
| V <sub>IL</sub> | Input Low Voltage  | -0.3 <sup>(1)</sup> | —    | 0.8      | V    |

3741tbl 02

### NOTE:

1. V<sub>IL</sub> (min.) = -1.5V for pulse width less than 20ns.

## Maximum Operating Temperature and Supply Voltage<sup>(1,2)</sup>

| Grade      | Ambient Temperature | GND | Vcc            |
|------------|---------------------|-----|----------------|
| Commercial | 0°C to +70°C        | 0V  | 3.3V $\pm$ 0.3 |
| Industrial | -40°C to +85°C      | 0V  | 3.3V $\pm$ 0.3 |

3741tbl 03

### NOTES:

1. This is the parameter T<sub>A</sub>. This is the "instant on" case temperature.  
 2. Industrial temperature: for specific speeds, packages and powers, contact your sales office.

## Capacitance<sup>(1)</sup> (T<sub>A</sub> = +25°C, f=1.0MHz)

| Symbol                          | Parameter          | Conditions <sup>(2)</sup> | Max. | Unit |
|---------------------------------|--------------------|---------------------------|------|------|
| C <sub>IN</sub>                 | Input Capacitance  | V <sub>IN</sub> = 3dV     | 9    | pF   |
| C <sub>OUT</sub> <sup>(3)</sup> | Output Capacitance | V <sub>OUT</sub> = 3dV    | 10   | pF   |

### NOTES:

1. This parameter is determined by device characterization but is not production tested.  
 2. 3dV references the interpolated capacitance when the input and output signals switch from 0V to 3V or from 3V to 0V.

3741tbl 04

## DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (V<sub>CC</sub> = 3.3V $\pm$ 0.3V)

| Symbol          | Parameter  | Test Conditions   | 71V30S |      | 71V30L |      | Unit |
|-----------------|--|---|--------|------|--------|------|------|
|                 |  |   | Min.   | Max. | Min.   | Max. |      |
| I <sub>L</sub>  | Input Leakage Current <sup>(1)</sup>                     | V <sub>CC</sub> = 3.6V,<br>V <sub>IN</sub> = 0V to V <sub>CC</sub>  | —      | 10   | —      | 5    | µA   |
| I <sub>LO</sub> | Output Leakage Current                                   | CĒ = V <sub>IH</sub> ,<br>V <sub>OUT</sub> = 0V to V <sub>CC</sub> | —      | 10   | —      | 5    | µA   |
| V <sub>OL</sub> | Output Low Voltage (I/O <sub>0</sub> -I/O <sub>7</sub> ) | I <sub>OL</sub> = 4mA   | —      | 0.4  | —      | 0.4  | V    |
| V <sub>OH</sub> | Output High Voltage                                      | I <sub>OH</sub> = -4mA  | 2.4    | —    | 2.4    | —    | V    |

### NOTE:

1. At V<sub>CC</sub>  $\leq$  2.0V input leakages are undefined.

3741tbl 05

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range<sup>(1,6,7)</sup> (V<sub>CC</sub> = 3.3V ± 0.3V)

| Symbol           | Parameter   | Test Condition   | Version | 71V30X25<br>Com'l Only |            | 71V30X35<br>Com'l & Ind |            | 71V30X55<br>Com'l Only |            | Unit       |    |
|------------------|---|--|---------|------------------------|------------|-------------------------|------------|------------------------|------------|------------|----|
|                  |   |  |         | Typ. <sup>(2)</sup>    | Max.       | Typ. <sup>(2)</sup>     | Max.       | Typ. <sup>(2)</sup>    | Max.       |            |    |
| I <sub>CC</sub>  | Dynamic Operating Current<br>(Both Ports Active)          | CE <sub>L</sub> and CER = V <sub>IL</sub> ,<br>Outputs Disabled<br>f = f <sub>MAX</sub> <sup>(3)</sup>   | COM'L   | S<br>L                 | 75<br>75   | 150<br>120              | 75<br>75   | 145<br>115             | 75<br>75   | 135<br>105 | mA |
|                  |   |  | IND     | S<br>L                 | —<br>—     | —<br>—                  | —<br>75    | —<br>145               | —<br>—     | —<br>—     |    |
| I <sub>SB1</sub> | Standby Current<br>(Both Ports - TTL Level<br>Inputs)     | CE <sub>L</sub> and CER = V <sub>IL</sub> ,<br>f = f <sub>MAX</sub> <sup>(3)</sup>   | COM'L   | S<br>L                 | 20<br>20   | 50<br>35                | 20<br>20   | 50<br>35               | 20<br>20   | 50<br>35   | mA |
|                  |   |  | IND     | S<br>L                 | —<br>—     | —<br>—                  | —<br>20    | —<br>50                | —<br>—     | —<br>—     |    |
| I <sub>SB2</sub> | Standby Current<br>(One Port - TTL Level<br>Inputs)       | CE <sup>A</sup> = V <sub>IL</sub> and CE <sup>B</sup> = V <sub>IH</sub> <sup>(5)</sup><br>Active Port Outputs Disabled,<br>f=f <sub>MAX</sub> <sup>(3)</sup>   | COM'L   | S<br>L                 | 30<br>30   | 105<br>75               | 30<br>30   | 100<br>70              | 30<br>30   | 90<br>60   | mA |
|                  |   |  | IND     | S<br>L                 | —<br>—     | —<br>—                  | —<br>30    | —<br>100               | —<br>—     | —<br>—     |    |
| I <sub>SB3</sub> | Full Standby Current (Both<br>Ports - CMOS Level Inputs)  | CE <sub>L</sub> and CER > V <sub>CC</sub> - 0.2V<br>V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2V or<br>V <sub>IN</sub> ≤ 0.2V, f = 0 <sup>(4)</sup>  | COM'L   | S<br>L                 | 1.0<br>0.2 | 5.0<br>3.0              | 1.0<br>0.2 | 5.0<br>3.0             | 1.0<br>0.2 | 5.0<br>3.0 | mA |
|                  |   |  | IND     | S<br>L                 | —<br>—     | —<br>—                  | —<br>1.0   | —<br>5.0               | —<br>—     | —<br>—     |    |
| I <sub>SB4</sub> | Full Standby Current<br>(One Port - CMOS<br>Level Inputs) | CE <sup>A</sup> ≤ 0.2V and<br>CE <sup>B</sup> ≥ V <sub>CC</sub> - 0.2V <sup>(5)</sup><br>V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2V or V <sub>IN</sub> ≤ 0.2V<br>Active Port Outputs Disabled<br>f=f <sub>MAX</sub> <sup>(3)</sup> | COM'L   | S<br>L                 | 30<br>30   | 90<br>75                | 30<br>30   | 85<br>70               | 30<br>30   | 75<br>60   | mA |
|                  |   |  | IND     | S<br>L                 | —<br>—     | —<br>—                  | —<br>30    | —<br>85                | —<br>—     | —<br>—     |    |

3741 tbl 06

NOTES:

- 'X' in part number indicates power rating (S or L)
- V<sub>CC</sub> = 3.3V, T<sub>A</sub> = +25°C, and are not production tested. I<sub>CCDC</sub> = 70mA (Typ.)
- At f = f<sub>MAX</sub>, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/t<sub>RC</sub>.
- f = 0 means no address or control lines change.
- Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- Refer to chip enable Truth Table I.
- Industrial temperature: for specific speeds, packages and powers contact your sales office.

Data Retention Characteristics (L Version Only)

| Symbol                          | Parameter                            | Test Condition   | 71V30L                         |                     |      | Unit |  |
|---------------------------------|--------------------------------------|--|--------------------------------|---------------------|------|------|--|
|                                 |                                      |  | Min.                           | Typ. <sup>(1)</sup> | Max. |      |  |
| V <sub>DR</sub>                 | V <sub>CC</sub> for Data Retention   | V <sub>CC</sub> = 2V, $\overline{CE} \geq V_{CC} - 0.2V$<br>V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2V or V <sub>IN</sub> ≤ 0.2V | 2.0                            | —                   | —    | V    |  |
| I <sub>CCDR</sub>               | Data Retention Current               |  | Ind.                           | —                   | 100  | 1000 |  |
| t <sub>CDR</sub> <sup>(3)</sup> | Chip Deselect to Data Retention Time |  | Com'l.                         | —                   | 100  | 500  |  |
|                                 |                                      |  | 0                              | —                   | —    | ns   |  |
| t <sub>R</sub> <sup>(3)</sup>   | Operation Recovery Time              |  | t <sub>RC</sub> <sup>(2)</sup> | —                   | —    | ns   |  |

3741 tbl 07

NOTES:

- V<sub>CC</sub> = 2V, T<sub>A</sub> = +25°C, and is not production tested.
- t<sub>RC</sub> = Read Cycle Time.
- This parameter is guaranteed by device characterization but not production tested.

## AC Test Conditions

|                               |                 |
|-------------------------------|-----------------|
| Input Pulse Levels            | GND to 3.0V     |
| Input Rise/Fall Times         | 3ns Max.        |
| Input Timing Reference Levels | 1.5V            |
| Output Reference Levels       | 1.5V            |
| Output Load                   | Figures 1 and 2 |

3741 tbl 08

## Data Retention Waveform

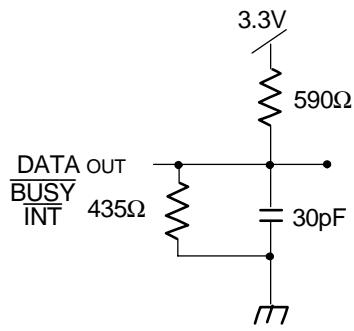
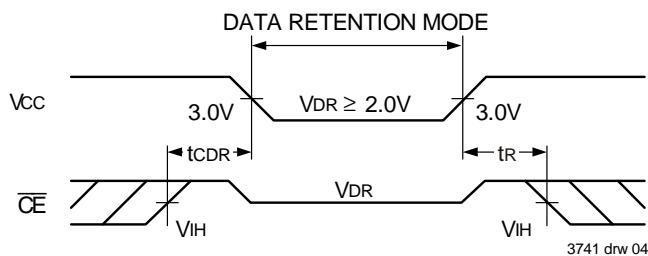


Figure 1. AC Output Test Load

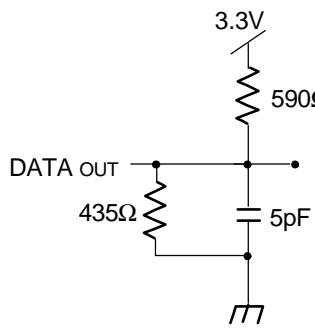


Figure 2. Output Test Load  
(For thz, tlz, twz and tow)

\* Including scope and jig.

## AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range<sup>(3,4)</sup>

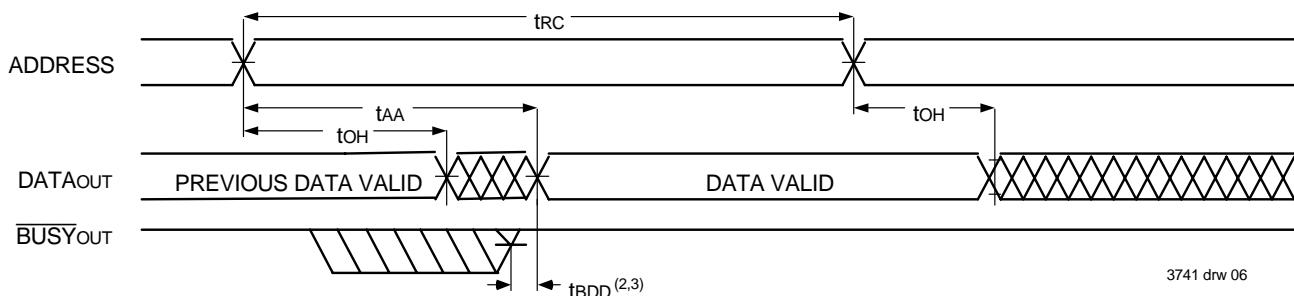
| Symbol            | Parameter                                      | 71V30X25<br>Com'l Only |      | 71V30X35<br>Com'l & Ind |      | 71V30X55<br>Com'l Only |      | Unit |
|-------------------|--|------------------------|------|-------------------------|------|------------------------|------|------|
|                   |  | Min.                   | Max. | Min.                    | Max. | Min.                   | Max. |      |
| <b>READ CYCLE</b> |  |                        |      |                         |      |                        |      |      |
| t <sub>RC</sub>   | Read Cycle Time                                | 25                     | —    | 35                      | —    | 55                     | —    | ns   |
| t <sub>AA</sub>   | Address Access Time                            | —                      | 25   | —                       | 35   | —                      | 55   | ns   |
| t <sub>ACE</sub>  | Chip Enable Access Time                        | —                      | 25   | —                       | 35   | —                      | 55   | ns   |
| t <sub>AOE</sub>  | Output Enable Access Time                      | —                      | 12   | —                       | 20   | —                      | 25   | ns   |
| t <sub>OH</sub>   | Output Hold from Address Change                | 3                      | —    | 3                       | —    | 3                      | —    | ns   |
| t <sub>lZ</sub>   | Output Low-Z Time <sup>(1,2)</sup>             | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| t <sub>hZ</sub>   | Output High-Z Time <sup>(1,2)</sup>            | —                      | 12   | —                       | 15   | —                      | 30   | ns   |
| t <sub>PU</sub>   | Chip Enable to Power Up Time <sup>(2)</sup>    | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| t <sub>PD</sub>   | Chip Disable to Power Down Time <sup>(2)</sup> | —                      | 50   | —                       | 50   | —                      | 50   | ns   |

3741 tbl 09

### NOTES:

1. Transition is measured 0mV from Low- or High-impedance voltage with Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization, but is not production tested.
3. 'X' in part number indicates power rating (S or L).
4. Industrial temperature: for specific speeds, packages and power contact your sales office.

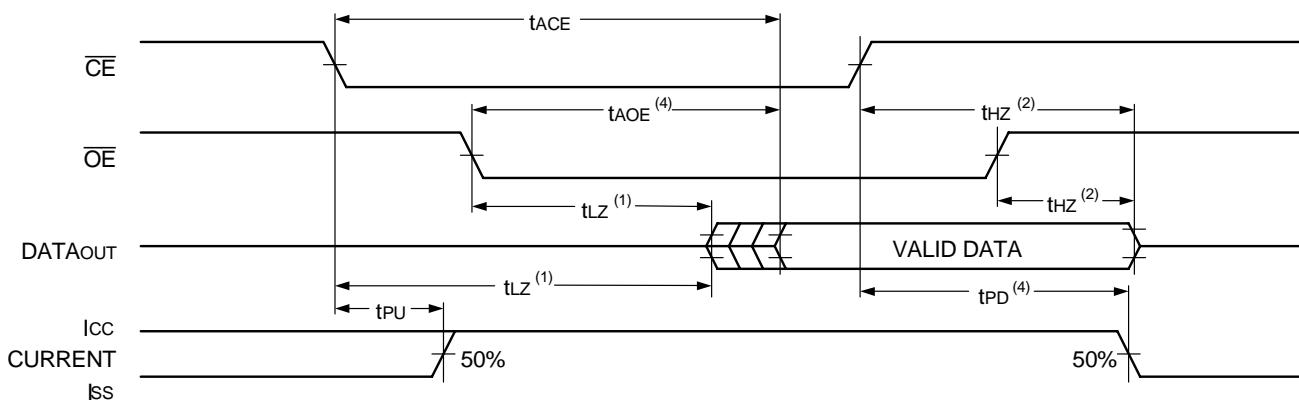
### Timing Waveform of Read Cycle No. 1, Either Side<sup>(1)</sup>



NOTES:

1.  $R/W = V_{IH}$ ,  $\overline{CE} = V_{IL}$ , and  $\overline{OE} = V_{IL}$ . Address is valid prior to the coincidental with  $\overline{CE}$  transition LOW.
2. tBDD delay is required only in case where the opposite port is completing a write operation to same the address location. For simultaneous read operations  $\overline{BUSY}$  has no relationship to valid output data.
3. Start of valid data depends on which timing becomes effective last tAOE, tACE, tAA, and tBDD.

### Timing Waveform of Read Cycle No. 2, Either Side<sup>(3)</sup>



NOTES:

1. Timing depends on which signal is asserted last,  $\overline{OE}$  or  $\overline{CE}$ .
2. Timing depends on which signal is deasserted first,  $\overline{OE}$  or  $\overline{CE}$ .
3.  $R/W = V_{IH}$  and the address is valid prior to or coincidental with  $\overline{CE}$  transition LOW.
4. Start of valid data depends on which timing becomes effective last tAOE, tACE, and tBDD.

AC Electrical Characteristics Over the  
Operating Temperature and Supply Voltage<sup>(4,5)</sup>

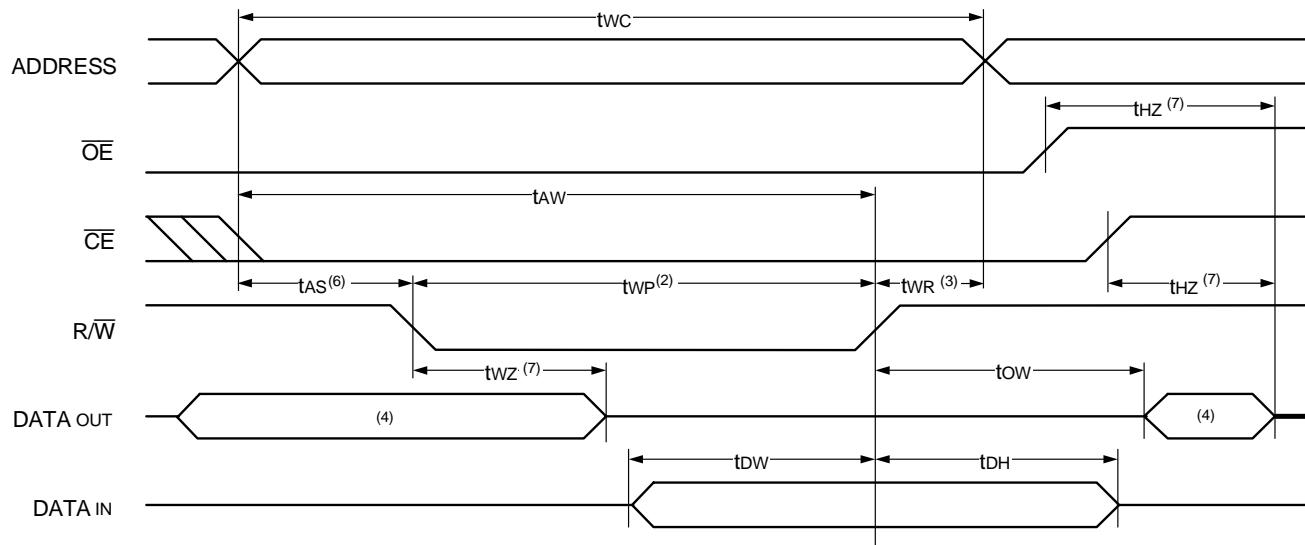
| Symbol             | Parameter  | 71V30X25<br>Com'l Only |      | 71V30X35<br>Com'l & Ind |      | 71V30X55<br>Com'l Only |      | Unit |
|--------------------|--|------------------------|------|-------------------------|------|------------------------|------|------|
|                    |  | Min.                   | Max. | Min.                    | Max. | Min.                   | Max. |      |
| <b>WRITE CYCLE</b> |  |                        |      |                         |      |                        |      |      |
| t <sub>WC</sub>    | Write Cycle Time                                   | 25                     | —    | 35                      | —    | 55                     | —    | ns   |
| t <sub>EW</sub>    | Chip Enable to End-of-Write                        | 20                     | —    | 30                      | —    | 40                     | —    | ns   |
| t <sub>AW</sub>    | Address Valid to End-of-Write                      | 20                     | —    | 30                      | —    | 40                     | —    | ns   |
| t <sub>AS</sub>    | Address Set-up Time                                | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| t <sub>WP</sub>    | Write Pulse Width                                  | 20                     | —    | 30                      | —    | 40                     | —    | ns   |
| t <sub>WR</sub>    | Write Recovery Time                                | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| t <sub>DW</sub>    | Data Valid to End-of-Write                         | 12                     | —    | 20                      | —    | 20                     | —    | ns   |
| t <sub>HZ</sub>    | Output High-Z Time <sup>(1,2)</sup>                | —                      | 12   | —                       | 15   | —                      | 30   | ns   |
| t <sub>DH</sub>    | Data Hold Time <sup>(3)</sup>                      | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| t <sub>WZ</sub>    | Write Enable to Output in High-Z <sup>(1,2)</sup>  | —                      | 15   | —                       | 15   | —                      | 30   | ns   |
| t <sub>OW</sub>    | Output Active from End-of-Write <sup>(1,2,3)</sup> | 0                      | —    | 0                       | —    | 0                      | —    | ns   |

3741 tbl 10

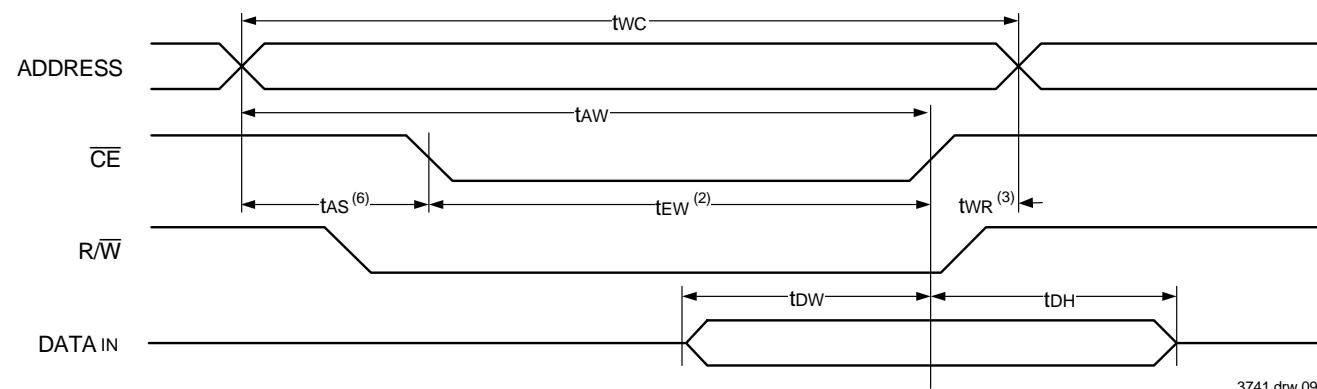
**NOTES:**

1. Transition is measured 0mV from Low- or High-impedance voltage with Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization, but is not production tested.
3. The specification for t<sub>DH</sub> must be met by the device supplying write data to the SRAM under all operating conditions. Although t<sub>DH</sub> and t<sub>OW</sub> values will vary over voltage and temperature, the actual t<sub>DH</sub> will always be smaller than the actual t<sub>OW</sub>.
4. 'X' in part number indicates power rating (S or L).
5. Industrial temperatures: for specific speeds, packages and powers contact your sales office.

Timing Waveform of Write Cycle No. 1, (R/W Controlled Timing)<sup>(1,5,8)</sup>



Timing Waveform of Write Cycle No. 2, CE Controlled Timing<sup>(1,5)</sup>



NOTES:

1. R/W or CE must be HIGH during all address transitions.
2. A write occurs during the overlap (tew or twp) of CE = VIL and R/W = VIL.
3. tWR is measured from the earlier of CE or R/W going HIGH to the end of the write cycle.
4. During this period, the I/O pins are in the output state and input signals must not be applied.
5. If the CE LOW transition occurs simultaneously with or after the R/W LOW transition, the outputs remain in the High-impedance state.
6. Timing depends on which enable signal (CE or R/W) is asserted last.
7. This parameter is determined by device characterization, but is not production tested. Transition is measured 0mV from steady state with the Output Test Load (Figure 2).
8. If OE is LOW during a R/W controlled write cycle, the write pulse width must be the larger of twp or (twz + tow) to allow the I/O drivers to turn off data to be placed on the bus for the required tow. If OE is HIGH during a R/W controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.

AC Electrical Characteristics Over the  
Operating Temperature and Supply Voltage Range<sup>(6,7)</sup>

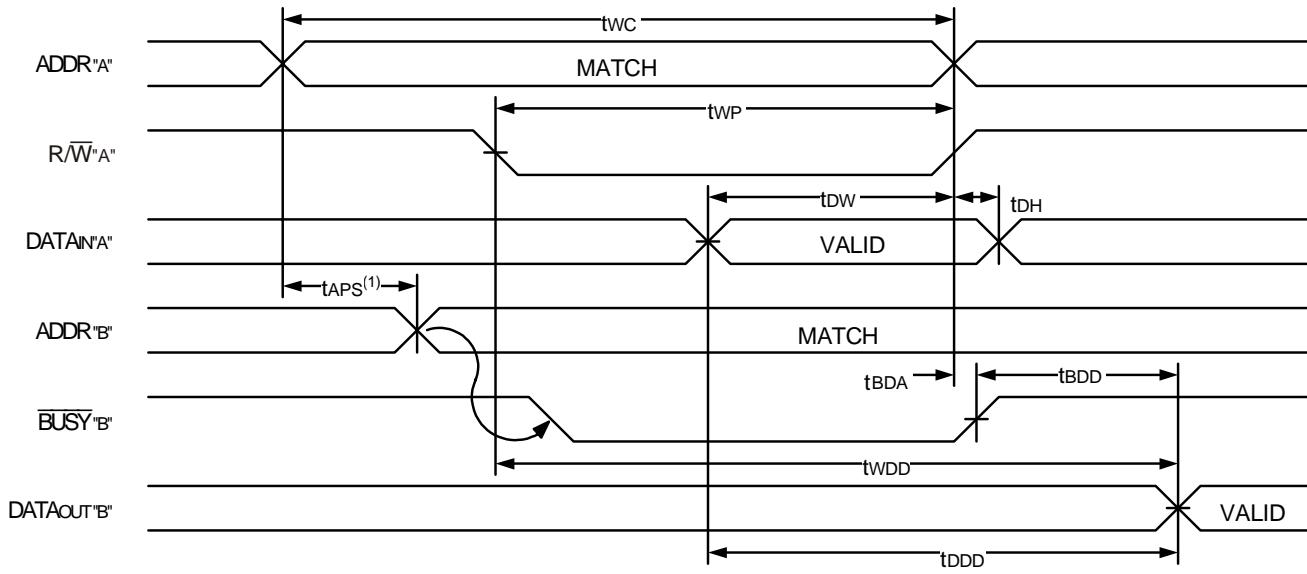
| Symbol                       | Parameter  | 71V30X25<br>Com'l Only |      | 71V30X35<br>Com'l & Ind |      | 71V30X55<br>Com'l Only |      | Unit |
|------------------------------|--|------------------------|------|-------------------------|------|------------------------|------|------|
|                              |  | Min.                   | Max. | Min.                    | Max. | Min.                   | Max. |      |
| <b>BUSY TIMING (M/S-VIH)</b> |  |                        |      |                         |      |                        |      |      |
| t <sub>BAA</sub>             | BUSY Access Time from Address Match                | —                      | 20   | —                       | 20   | —                      | 30   | ns   |
| t <sub>BDA</sub>             | BUSY Disable Time from Address Not Matched         | —                      | 20   | —                       | 20   | —                      | 30   | ns   |
| t <sub>BAC</sub>             | BUSY Access Time from Chip Enable                  | —                      | 20   | —                       | 20   | —                      | 30   | ns   |
| t <sub>BDC</sub>             | BUSY Disable Time from Chip Enable                 | —                      | 20   | —                       | 20   | —                      | 30   | ns   |
| t <sub>WH</sub>              | Write Hold After BUSY <sup>(5)</sup>               | 20                     | —    | 30                      | —    | 40                     | —    | ns   |
| t <sub>WDD</sub>             | Write Pulse to Data Delay <sup>(1)</sup>           | —                      | 50   | —                       | 60   | —                      | 80   | ns   |
| t <sub>DDD</sub>             | Write Data Valid to Read Data Delay <sup>(1)</sup> | —                      | 35   | —                       | 45   | —                      | 65   | ns   |
| t <sub>APS</sub>             | Arbitration Priority Set-up Time <sup>(2)</sup>    | 5                      | —    | 5                       | —    | 5                      | —    | ns   |
| t <sub>BDD</sub>             | BUSY Disable to Valid Data <sup>(3)</sup>          | —                      | 30   | —                       | 30   | —                      | 45   | ns   |

3741 tbl 11

NOTES:

1. Port-to-port delay through SRAM cells from writing port to reading port, refer to "Timing Waveform of Write with Port-to-Port Read with BUSY".
2. To ensure that the earlier of the two ports wins.
3. t<sub>BDD</sub> is a calculated parameter and is the greater of 0, t<sub>WDD</sub> – t<sub>WP</sub> (actual) or t<sub>DDD</sub> – t<sub>BW</sub> (actual).
4. To ensure that the Write Cycle is inhibited on Port "B" during contention on Port "A".
5. To ensure that the Write Cycle is completed on Port "B" after contention on Port "A".
6. 'X' in part number indicates power rating (S or L).
7. Industrial temperature: for specific speeds, packages and powers contact your sales office.

Timing Waveform of Write with Port-to-Port Read with **BUSY**<sup>(1,2,3,4)</sup>

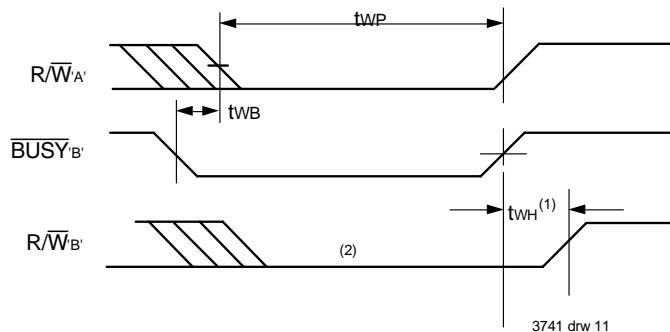


3741 drw 10

NOTES:

1. To ensure that the earlier of the two ports wins.
2.  $\overline{CE}_L = \overline{CE}_R = V_{IL}$
3.  $\overline{OE} = V_{IL}$  for the reading port.
4. All timing is the same for the left and right ports. Port 'A' may be either the left or right port. Port "B" is opposite from port "A".

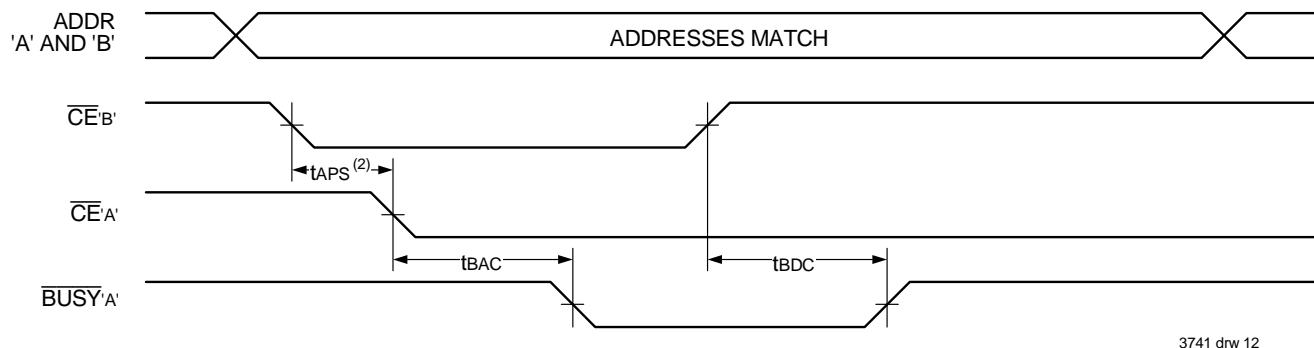
### Timing Waveform of Write with **BUSY**<sup>(3)</sup>



**NOTES:**

1. **tWH** must be met for **BUSY**.
2. **BUSY** is asserted on port 'B' blocking **R/W<sub>B'</sub>**, until **BUSY<sub>B'</sub>** goes HIGH.
3. All timing is the same for the left and right ports. Port "A" may be either the left or right port. Port "B" is opposite from port "A".

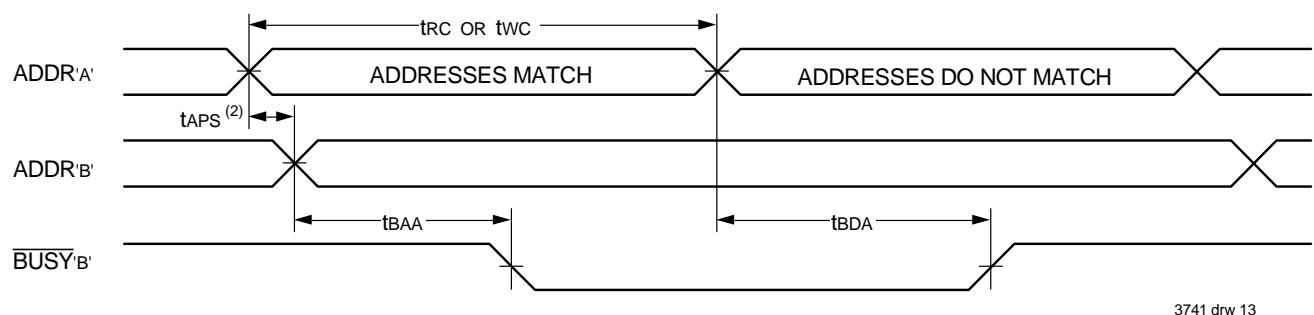
### Timing Waveform of **BUSY** Arbitration Controlled by **CE** Timing<sup>(1)</sup>



**NOTES:**

1. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
2. If **tAPS** is not satisfied, the **BUSY** will be asserted on one side or the other, but there is no guarantee on which side **BUSY** will be asserted.

### Timing Waveform of **BUSY** Arbitration Controlled Address Match Timing<sup>(1)</sup>



**NOTES:**

1. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
2. If **tAPS** is not satisfied, the **BUSY** will be asserted on one side or the other, but there is no guarantee on which side **BUSY** will be asserted.

AC Electrical Characteristics Over the  
Operating Temperature and Supply Voltage Range<sup>(1,2)</sup>

| Symbol                  | Parameter            | 71V30X25<br>Com'l Only |      | 71V30X35<br>Com'l & Ind |      | 71V30X55<br>Com'l Only |      | Unit |
|-------------------------|----------------------|------------------------|------|-------------------------|------|------------------------|------|------|
|                         |                      | Min.                   | Max. | Min.                    | Max. | Min.                   | Max. |      |
| <b>INTERRUPT TIMING</b> |                      |                        |      |                         |      |                        |      |      |
| tas                     | Address Set-up Time  | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| tWR                     | Write Recovery Time  | 0                      | —    | 0                       | —    | 0                      | —    | ns   |
| tINS                    | Interrupt Set Time   | —                      | 25   | —                       | 25   | —                      | 45   | ns   |
| tINR                    | Interrupt Reset Time | —                      | 25   | —                       | 25   | —                      | 45   | ns   |

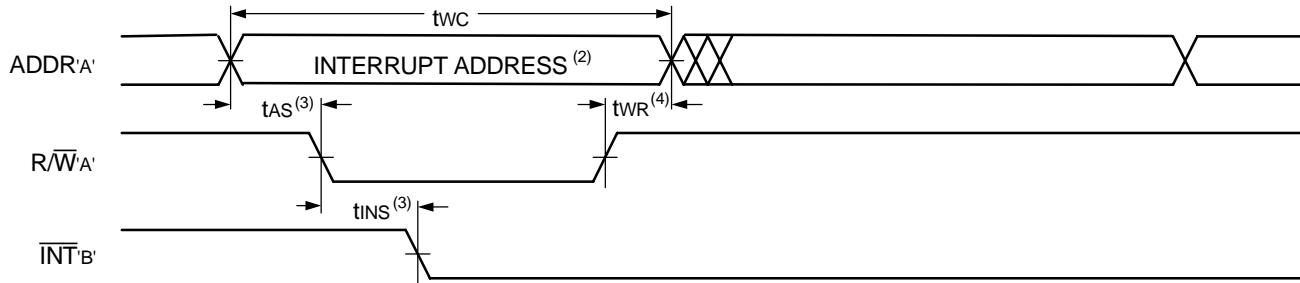
3741 tbl 12

NOTES:

1. 'X' in part number indicates power rating (S or L).
2. Industrial temperature: for specific speeds, packages and powers contact your sales office.

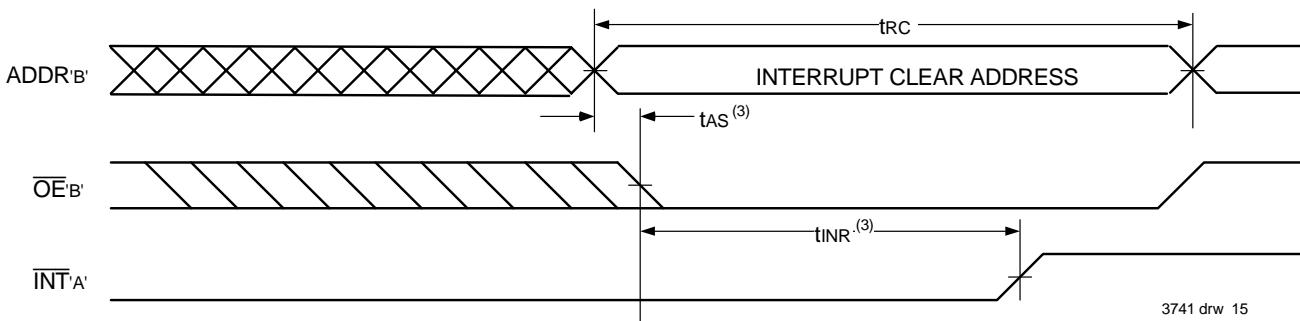
Timing Waveform of Interrupt Mode<sup>(1)</sup>

**INT** Sets



3741 drw 14

**INT** Clears



3741 drw 15

NOTES:

1. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
2. See Interrupt Truth Table II.
3. Timing depends on which enable signal ( $\overline{CE}$  or  $\overline{R/W}$ ) is asserted last.
4. Timing depends on which enable signal ( $\overline{CE}$  or  $\overline{R/W}$ ) is de-asserted first.

## Truth Tables

Table I — Non-Contention Read/Write Control<sup>(4)</sup>

| Left or Right Port <sup>(1)</sup> |    |    |         | Function  |
|-----------------------------------|----|----|---------|---|
| R/W                               | CE | OE | D0-7    |   |
| X                                 | H  | X  | Z       | Port Disabled and in Power-Down Mode, lsb2 or lsb4                                  |
| X                                 | H  | X  | Z       | CE <sub>R</sub> = CE <sub>L</sub> = V <sub>ih</sub> , Power-Down Mode, lsb1 or lsb3 |
| L                                 | L  | X  | DATAIN  | Data on Port Written Into Memory <sup>(2)</sup>                                     |
| H                                 | L  | L  | DATAOUT | Data in Memory Output on Port <sup>(3)</sup>  |
| H                                 | L  | H  | Z       | High Impedance Outputs  |

3741tbl 13

NOTES:

1. AOL - A9L  $\neq$  A0R - A9R.
2. If  $\overline{\text{BUSY}} = L$ , data is not written.
3. If  $\overline{\text{BUSY}} = L$ , data may not be valid, see t<sub>WDD</sub> and t<sub>DOD</sub> timing.
4. 'H' = V<sub>ih</sub>, 'L' = V<sub>il</sub>, 'X' = DON'T CARE, 'Z' = HIGH IMPEDANCE

Table II — Interrupt Flag<sup>(1,4)</sup>

| Left Port        |                 |                 |         |                  | Right Port       |                 |                 |         |                  | Function              |
|------------------|-----------------|-----------------|---------|------------------|------------------|-----------------|-----------------|---------|------------------|-----------------------|
| R/W <sub>L</sub> | CE <sub>L</sub> | OE <sub>L</sub> | A9L-A0L | INTL             | R/W <sub>R</sub> | CE <sub>R</sub> | OE <sub>R</sub> | A0R-A0R | INTR             |                       |
| L                | L               | X               | 3FF     | X                | X                | X               | X               | X       | L <sup>(2)</sup> | Set Right INTR Flag   |
| X                | X               | X               | X       | X                | X                | L               | L               | 3FF     | H <sup>(3)</sup> | Reset Right INTR Flag |
| X                | X               | X               | X       | L <sup>(3)</sup> | L                | L               | X               | 3FE     | X                | Set Left INTL Flag    |
| X                | L               | L               | 3FE     | H <sup>(2)</sup> | X                | X               | X               | X       | X                | Reset Left INTL Flag  |

3741tbl 14

NOTES:

1. Assumes  $\overline{\text{BUSY}}_L = \overline{\text{BUSY}}_R = V_{ih}$
2. If  $\overline{\text{BUSY}}_L = V_{il}$ , then No Change.
3. If  $\overline{\text{BUSY}}_R = V_{il}$ , then No Change.
4. 'H' = HIGH, 'L' = LOW, 'X' = DON'T CARE

Table III — Address **BUSY** Arbitration

| Inputs          |                 |                    | Outputs                          |                                  | Function                     |
|-----------------|-----------------|--------------------|----------------------------------|----------------------------------|------------------------------|
| CE <sub>L</sub> | CE <sub>R</sub> | A0L-A9L<br>A0R-A9R | BUSY <sub>L</sub> <sup>(1)</sup> | BUSY <sub>R</sub> <sup>(1)</sup> |                              |
| X               | X               | NO MATCH           | H                                | H                                | Normal                       |
| H               | X               | MATCH              | H                                | H                                | Normal                       |
| X               | H               | MATCH              | H                                | H                                | Normal                       |
| L               | L               | MATCH              | (2)                              | (2)                              | Write Inhibit <sup>(3)</sup> |

3741tbl 15

NOTES:

1. Pins  $\overline{\text{BUSY}}_L$  and  $\overline{\text{BUSY}}_R$  are both outputs for IDT71V30.  $\overline{\text{BUSY}}_x$  outputs on the IDT71V30 are non-tristate push-pull.
2. 'L' if the inputs to the opposite port were stable prior to the address and enable inputs of this port. 'H' if the inputs to the opposite port became stable after the address and enable inputs of this port. If t<sub>APS</sub> is not met, either  $\overline{\text{BUSY}}_L$  or  $\overline{\text{BUSY}}_R = \text{LOW}$  will result.  $\overline{\text{BUSY}}_L$  and  $\overline{\text{BUSY}}_R$  outputs can not be LOW simultaneously.
3. Writes to the left port are internally ignored when  $\overline{\text{BUSY}}_L$  outputs are driving LOW regardless of actual logic level on the pin. Writes to the right port are internally ignored when  $\overline{\text{BUSY}}_R$  outputs are driving LOW regardless of actual logic level on the pin.

## Functional Description

The IDT71V30 provides two ports with separate control, address and I/O pins that permit independent access for reads or writes to any location in memory. The IDT71V30 has an automatic power down feature controlled by CE. The CE controls on-chip power down circuitry that permits the respective port to go into a standby mode when not selected ( $\overline{CE} = V_{IH}$ ). When a port is enabled, access to the entire memory array is permitted.

## Interrupts

If the user chooses the interrupt function, a memory location (mail box or message center) is assigned to each port. The left port interrupt flag ( $\overline{INT}_L$ ) is asserted when the right port writes to memory location 3FE (HEX), where a write is defined as the  $\overline{CE} = R/W = V_{IL}$  per Truth Table II. The left port clears the interrupt by accessing address location 3FE access with  $\overline{CE}_R = \overline{OE}_R = V_{IL}, R/W$  is a "don't care". Likewise, the right port interrupt flag ( $\overline{INT}_R$ ) is asserted when the left port writes to memory location 3FF (HEX) and to clear the interrupt flag ( $\overline{INT}_R$ ), the right port must access the memory location 3FF. The message (8 bits)

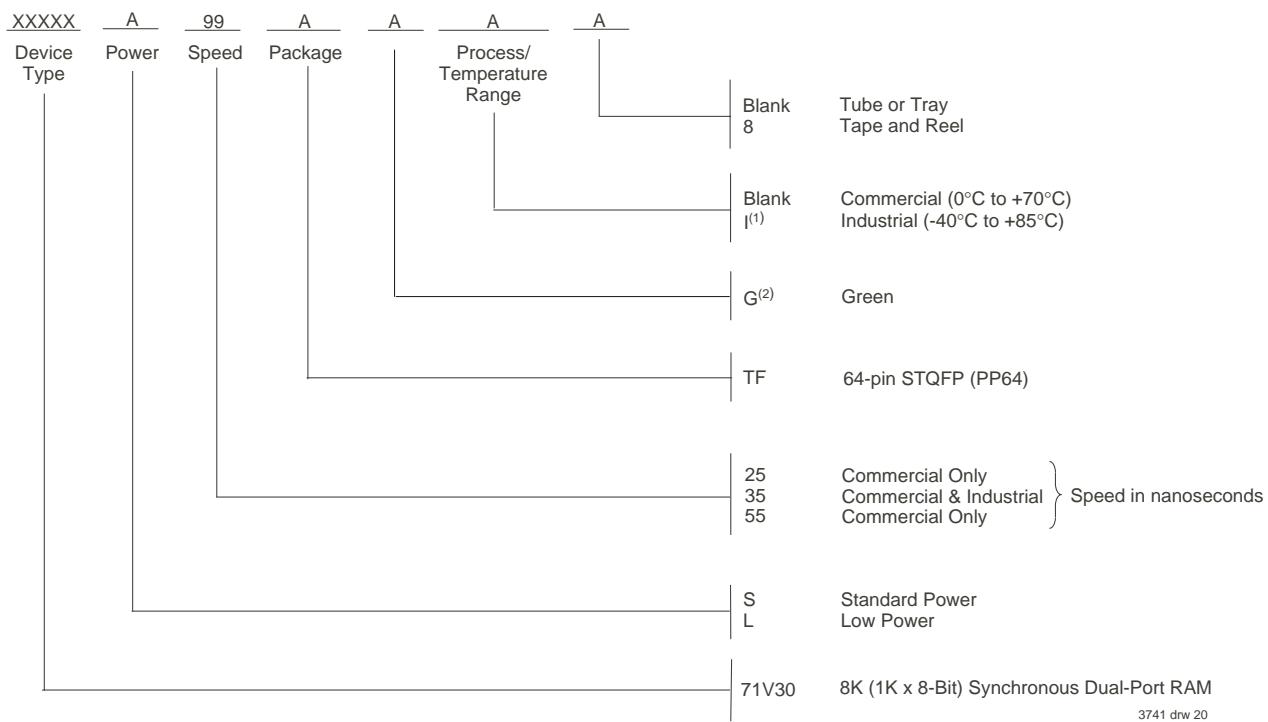
at 3FE or 3FF is user-defined, since it is an addressable SRAM location. If the interrupt function is not used, address locations 3FE and 3FF are not used as mail boxes, and are part of the random access memory. Refer to Table II for the interrupt operation.

## Busy Logic

Busy Logic provides a hardware indication that both ports of the SRAM have accessed the same location at the same time. It also allows one of the two accesses to proceed and signals the other side that the SRAM is "Busy". The  $\overline{BUSY}$  pin can then be used to stall the access until the operation on the other side is completed. If a write operation has been attempted from the side that receives a  $\overline{BUSY}$  indication, the write signal is gated internally to prevent the write from proceeding.

The use of  $\overline{BUSY}$  logic is not required or desirable for all applications. In some cases it may be useful to logically OR the  $\overline{BUSY}$  outputs together and use any  $\overline{BUSY}$  indication as an interrupt source to flag the event of an illegal or illogical operation.

## Ordering Information



### NOTES:

1. Industrial temperature range is available. For specific speeds, packages and powers contact your sales office.
2. Green parts available. For specific speeds, packages and powers contact your sales office.

**LEAD FINISH (SnPb) parts are in EOL process. Product Discontinuation Notice - PDN# SP-17-02**

## Datasheet Document History

12/9/98:      Initiated datasheet document history  
                    Converted to new format  
                    Cosmetic and typographical corrections  
                    Added additional notes to pin configurations

6/15/99:      Changed drawing format

8/3/99:      Page 2   Fixed typographical error

9/1/99:      Removed Preliminary

11/12/99:      Replaced IDT logo

1/17/01:      Pages 1 and 2 Moved all of "Description" to page 2 and adjusted page layouts  
                    Page 3   Increased storage temperature parameters  
                    Clarified TA parameter  
                    Page 4   DC Electrical parameters—changed wording from "open" to "disabled"  
                    Changed  $\pm 200$ mV to 0mV in notes

3/14/05:      Page 1   Added green availability to features  
                    Page 17   Added green indicator to ordering information  
                    Page 1 & 17 Replaced old <sup>TM</sup> logo with new <sup>TM</sup> logo

7/16/07:      Page 3   Added Junction Temperature spec values to the Absolute Maximum Rating table  
                    Added footnote 3 for additional clarification of Junction Temperature

## Datasheet Document History (con't)

|           |                  |   |
|-----------|------------------|---|
| 10/23/08: | Page 14          | Removed "IDT" from orderable part number  |
| 11/25/09: | Page 4           | In order to correct the DC Chars table for the 71V30L35 speed grade and to the Data Retention Chars table, I Temp values have been added to each table respectively. In addition, all of the AC tables and the ordering information also now reflect this I temp correction |
| 06/22/15: | Page 2           | Removed IDT in reference to fabrication   |
|           | Page 2 & 14      | The package code PP64-1 changed to PP64 to match standard package codes   |
|           | Page 14          | Added Tape and Reel indicator to Ordering Information   |
| 07/23/15: | Entire datasheet | Removed the 55ns Industrial speed offering. 55ns speed only offered in commercial grade   |
| 12/20/17: |                  | Product Discontinuation Notice - PDN# SP-17-02  |
|           |                  | Last time buy expires June 15, 2018   |



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